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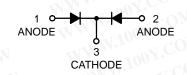
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# 30 VOLT DUAL COMMON CATHODE SCHOTTKY BARRIER DIODES



#### MARKING DIAGRAM



SC-75 CASE 463 STYLE 3



5C = Device Code

M = Date Code\*

■ Pb–Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

	Device	Package	Shipping <sup>†</sup>
4	BAT54CTT1	SC-75	3000 / Tape & Reel
	BAT54CTT1G	SC-75 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

# **Dual Series Schottky Barrier Diodes**

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

**Preferred Device** 

#### **Features**

- Extremely Fast Switching Speed
- Low Forward Voltage -0.35 Volts (Typ) @  $I_F = 10$  mAdc
- Pb-Free Package is Available

## **MAXIMUM RATINGS** (T<sub>J</sub> = 125°C unless otherwise noted)

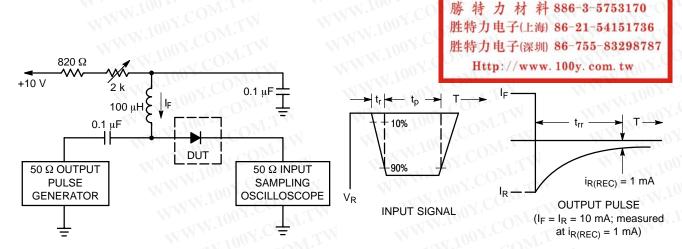
Rating	Symbol	Value	Unit
Reverse Voltage	$V_{R}$	30	V
Forward Power Dissipation  @ T <sub>A</sub> = 25°C  Derate above 25°C	OM P <sub>F</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	555	°C/W
Forward Current (DC)	I <sub>F</sub>	200 Max	mA
Junction Temperature	(CT)	-55 to 125	°C
Storage Temperature Range	T <sub>stg</sub>	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

FR-4 board with minimum mounting pad.

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I <sub>R</sub> = 10 μA)	V <sub>(BR)R</sub>	30	CON	IV-	V
Total Capacitance (V <sub>R</sub> = 1.0 V, f = 1.0 MHz)	C <sub>T</sub>	WW <del>-</del> 100	7.6	10	pF
Reverse Leakage (V <sub>R</sub> = 25 V)	IR IR	MAN.	0.5	2.0	μAdc
Forward Voltage (I <sub>F</sub> = 0.1 mAdc)	V <sub>F</sub>	WWW	0.22	0.24	Vdc
Forward Voltage (I <sub>F</sub> = 30 mAdc)	V <sub>F</sub>	WWI	0.41	0.5	Vdc
Forward Voltage (I <sub>F</sub> = 100 mAdc)	V <sub>F</sub>	Thu.	0.52	0.8	Vdc
Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ mAdc}, Figure 1)$	COM t <sub>rr</sub>	- 1/	NAT.	5.0	ns
Forward Voltage (I <sub>F</sub> = 1.0 mAdc)	V <sub>F</sub>	_ 1	0.29	0.32	Vdc
Forward Voltage (I <sub>F</sub> = 10 mAdc)	V <sub>F</sub>	- W	0.35	0.40	Vdc
Forward Current (DC)	Y.CIF	- W	15 M	200	mAdc
Repetitive Peak Forward Current	I <sub>FRM</sub>	TW-	WW	300	mAdc
Non-Repetitive Peak Forward Current (t < 1.0 s)	I <sub>FSM</sub>	I.TW	- 11	600	mAdc



Notes: 1. A 2.0  $k\Omega$  variable resistor adjusted for a Forward Current (I\_F) of 10 mA.

- 2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 10 mA.
- 3.  $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

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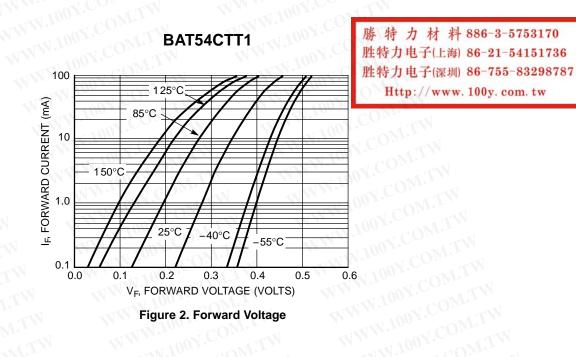


Figure 2. Forward Voltage

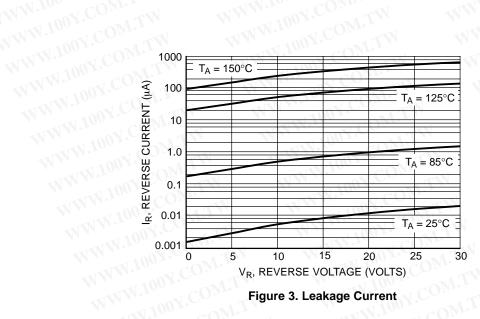


Figure 3. Leakage Current

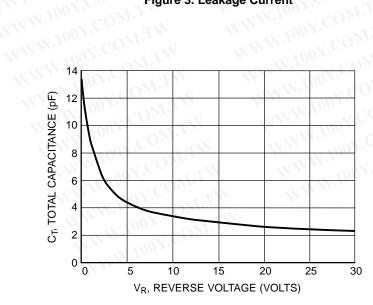
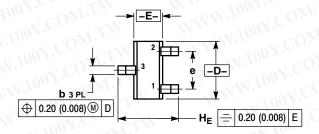
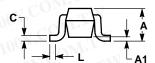


Figure 4. Total Capacitance

### **PACKAGE DIMENSIONS**

SC-75 / SOT-416 PLASTIC PACKAGE CASE 463-01 ISSUE F 勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-54151736 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.

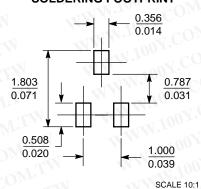
	MILLIMETERS INCHES			1		
DIM	MIN	MOM	MAX	MIN	NOM	MAX
Α	0.70	0.80	0.90	0.027	0.031	0.035
A1	0.00	0.05	0.10	0.000	0.002	0.004
b	0.15	0.20	0.30	0.006	0.008	0.012
С	0.10	0.15	0.25	0.004	0.006	0.010
D	1.55	1.60	1.65	0.059	0.063	0.067
Е	0.70	0.80 0.90 0.02		0.027	0.031	0.035
е	1.00 BSC			0.04 BSC		
L	0.10	0.15	0.20	0.004	0.006	0.008
He	1.50	1.60	1.70	0.061	0.063	0.065

STYLE 3: PIN 1. ANODE

mm \

2. ANODE 3. CATHODE

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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